## NSN 5961-00-581-6191

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No Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-00-581-6191 **Inclosure Material:** Glass and metal **Overall Length:** Between 0.170 inches and 0.210 inches **Terminal Length:** 0.500 inches **Overall Diameter:** Between 0.209 inches and 0.230 inches **Internal Configuration:** Field effect Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-18 **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 40.0 drain to gate voltage and 40.0 drain to source voltage and -40.0 gate to source voltage **Current Rating Per Characteristic:** 50.00 milliamperes gate current **Power Rating Per Characteristic:** 360.0 milliwatts total power dissipation **Test Data Document:** 58189-v00709 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 3 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:**